

Vishay General Semiconductor

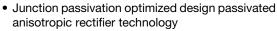
Surface Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



| PRIMARY CHARACTERISTICS | | | | |
|-----------------------------------|--------------|--|--|--|
| V_{WM} | 10 V to 43 V | | | |
| P _{PPM} (10 x 1000 μs) | 6600 W | | | |
| P _{PPM} (10 x 10 000 μs) | 5200 W | | | |
| P _D | 8 W | | | |
| I _{FSM} | 700 A | | | |
| T _J max. | 175 °C | | | |

FEATURES





 T_J = 175 °C capability suitable for high reliability and automotive requirement

RoHS

- · Available in uni-directional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Ing. rearge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Heatsink is anode

| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|-----------------------------------|------------------|------|---|--|--|
| PARAMETER | SYMBOL | VALUE | UNIT | | | |
| Peak pulse power dissipation | with 10/1000 μs waveform | P _{PPM} | 6600 | W | | |
| | with 10/10 000 μs waveform | | 5200 | | | |
| Power dissipation on infini | P _D | 8.0 | W | | | |
| Peak pulse current with 10/1000 µ | I _{PPM} ⁽¹⁾ | See next table | Α | | | |
| Peak forward surge current 8.3 m | I _{FSM} | 700 | А | | | |
| Operating junction and storage te | T _J , T _{STG} | - 55 to + 175 | °C | | | |

Note

⁽¹⁾ Non-repetitive current pulse derated above $T_A = 25 \,^{\circ}\text{C}$



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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | | |
|--|------|---------------|-----------------------------------|---|---|---|--|---|
| TYPE V _{BR} | | TAGE R (V) | TEST CURRENT I _T | STAND-OFF VOLTAGE V _{WM} | MAXIMUM REVERSE LEAKAGE AT V _{WM} | MAXIMUM REVERSE LEAKAGE AT V _{WM} T _J = 175 °C | MAX. PEAK PULSE CURRENT AT 10/1000 µs WAVEFORM | MAXIMUM CLAMPING VOLTAGE AT I _{PPM} |
| | MIN. | MAX. | (mA) | (V) | I _D (μA) | Ĭ _D (μA) | (A) | V _C (V) |
| SM8S10 | 11.1 | 13.6 | 5.0 | 10.0 | 15 | 250 | 351 | 18.8 |
| SM8S10A | 11.1 | 12.3 | 5.0 | 10.0 | 15 | 250 | 388 | 17.0 |
| SM8S11 | 12.2 | 14.9 | 5.0 | 11.0 | 10 | 150 | 328 | 20.1 |
| SM8S11A | 12.2 | 13.5 | 5.0 | 11.0 | 10 | 150 | 363 | 18.2 |
| SM8S12 | 13.3 | 16.3 | 5.0 | 12.0 | 10 | 150 | 300 | 22.0 |
| SM8S12A | 13.3 | 14.7 | 5.0 | 12.0 | 10 | 150 | 332 | 19.9 |
| SM8S13 | 14.4 | 17.6 | 5.0 | 13.0 | 10 | 150 | 277 | 23.8 |
| SM8S13A | 14.4 | 15.9 | 5.0 | 13.0 | 10 | 150 | 307 | 21.5 |
| SM8S14 | 15.6 | 19.1 | 5.0 | 14.0 | 10 | 150 | 256 | 25.8 |
| SM8S14A | 15.6 | 17.2 | 5.0 | 14.0 | 10 | 150 | 284 | 23.2 |
| SM8S15 | 16.7 | 20.4 | 5.0 | 15.0 | 10 | 150 | 245 | 26.9 |
| SM8S15A | 16.7 | 18.5 | 5.0 | 15.0 | 10 | 150 | 270 | 24.4 |
| SM8S16 | 17.8 | 21.8 | 5.0 | 16.0 | 10 | 150 | 229 | 28.8 |
| SM8S16A | 17.8 | 19.7 | 5.0 | 16.0 | 10 | 150 | 254 | 26.0 |
| SM8S17 | 18.9 | 23.1 | 5.0 | 17.0 | 10 | 150 | 216 | 30.5 |
| SM8S17A | 18.9 | 20.9 | 5.0 | 17.0 | 10 | 150 | 239 | 27.6 |
| SM8S18 | 20.0 | 24.4 | 5.0 | 18.0 | 10 | 150 | 205 | 32.2 |
| SM8S18A | 20.0 | 22.1 | 5.0 | 18.0 | 10 | 150 | 226 | 29.2 |
| SM8S20 | 22.2 | 27.1 | 5.0 | 20.0 | 10 | 150 | 184 | 35.8 |
| SM8S20A | 22.2 | 24.5 | 5.0 | 20.0 | 10 | 150 | 204 | 32.4 |
| SM8S22 | 24.4 | 29.8 | 5.0 | 22.0 | 10 | 150 | 168 | 39.4 |
| SM8S22A | 24.4 | 26.9 | 5.0 | 22.0 | 10 | 150 | 186 | 35.5 |
| SM8S24 | 26.7 | 32.6 | 5.0 | 24.0 | 10 | 150 | 153 | 43.0 |
| SM8S24A | 26.7 | 29.5 | 5.0 | 24.0 | 10 | 150 | 170 | 38.9 |
| SM8S26 | 28.9 | 35.3 | 5.0 | 26.0 | 10 | 150 | 142 | 46.6 |
| SM8S26A | 28.9 | 31.9 | 5.0 | 26.0 | 10 | 150 | 157 | 42.1 |
| SM8S28 | 31.1 | 38.0 | 5.0 | 28.0 | 10 | 150 | 132 | 50.1 |
| SM8S28A | 31.1 | 34.4 | 5.0 | 28.0 | 10 | 150 | 145 | 45.4 |
| SM8S30 | 33.3 | 40.7 | 5.0 | 30.0 | 10 | 150 | 123 | 53.5 |
| SM8S30A | 33.3 | 36.8 | 5.0 | 30.0 | 10 | 150 | 136 | 48.4 |
| SM8S33 | 36.7 | 44.9 | 5.0 | 33.0 | 10 | 150 | 112 | 59.0 |
| SM8S33A | 36.7 | 40.6 | 5.0 | 33.0 | 10 | 150 | 124 | 53.3 |
| SM8S36 | 40.0 | 48.9 | 5.0 | 36.0 | 10 | 150 | 103 | 64.3 |
| SM8S36A | 40.0 | 44.2 | 5.0 | 36.0 | 10 | 150 | 114 | 58.1 |
| SM8S40 | 44.4 | 54.3 | 5.0 | 40 | 10 | 150 | 92.4 | 71.4 |
| SM8S40A | 44.4 | 49.1 | 5.0 | 40 | 10 | 150 | 102 | 64.5 |
| SM8S43 | 47.8 | 58.4 | 5.0 | 43 | 10 | 150 | 86 | 76.7 |
| SM8S43A | 47.8 | 52.8 | 5.0 | 43 | 10 | 150 | 95.1 | 69.4 |

Note

For all types maximum V_F = 1.8 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses
per minute maximum



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| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | |
|---|----------------|-------|------|--|--|
| PARAMETER | SYMBOL | VALUE | UNIT | | |
| Typical thermal resistance, junction to case | $R_{	heta JC}$ | 0.90 | °C/W | | |

| ORDERING INFORMATION (Example) | | | | | |
|--|-------|---------------|---------------|---|--|
| PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE | | BASE QUANTITY | DELIVERY MODE | | |
| SM8S10AHE3/2D (1) | 2.605 | 2D | 750 | 13" diameter plastic tape and reel, anode towards the sprocket hole | |

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

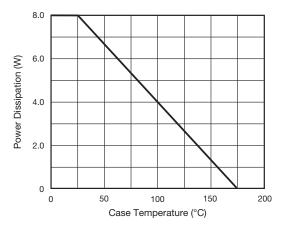


Fig. 1 - Power Derating Curve

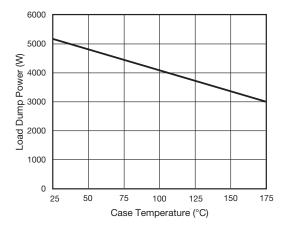


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

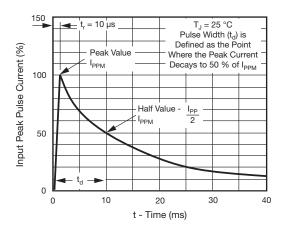


Fig. 3 - Pulse Waveform

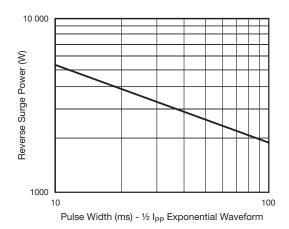


Fig. 4 - Reverse Power Capability

⁽¹⁾ AEC-Q101 qualified



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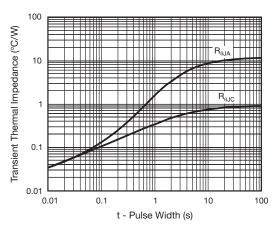


Fig. 5 - Typical Transient Thermal Impedance

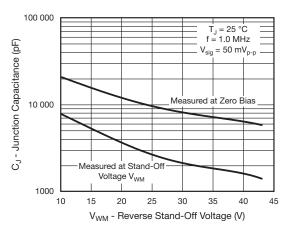
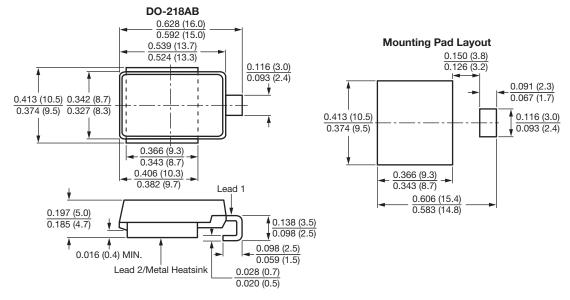


Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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